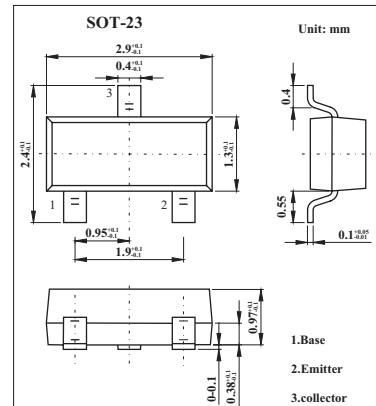


FMMT2484

■ Features

- 60 Volt V_{CEO}.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CEO}	60	V
Emitter-base voltage	V _{EBO}	6	V
Peak collector current	I _{CM}	200	mA
Collector current	I _C	50	mA
Power dissipation	P _{tot}	330	mW
Operating and storage temperature range	T _j , T _{stg}	-55 to +150	°C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =10µA, I _E =0	60			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA, I _B =0	60			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10µA, I _C =0	6			V
Collector cutoff current	I _{CBO}	V _{CB} =45V, I _E =0			10	nA
		V _{CB} =45V, T _{amb} =150°C			10	µA
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0			10	nA
Collector-emitter saturation voltage *	V _{CE(sat)}	I _C =1A, I _B =100µA			0.35	V
Base-emitter voltage *	V _{BE}	I _C =1A, V _{CE} =5V			0.95	V
DC current gain *	h _{FE}	I _C =10µA, V _{CE} =5V	100		500	
Output capacitance	C _{obo}	V _{CB} =5V, f=140KHz			6	pF
Input capacitance	C _{iob}	V _{BE} =0.5V, f=140KHz			6	pF
Output capacitance	NF	I _C =200µA, V _{CE} =5V, R _g =2kΩ f=1kHz, f=200Hz			3	dB
		I _C =200µA, V _{CE} =5V, R _g =2kΩ f=30Hz to 15kHz at -3dB points			3	dB

* Pulse test: t_p ≤ 300µs; d ≤ 0.02.

■ Marking

Marking	4G
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